

# TrenchP<sup>™</sup> Power MOSFET

IXTT76P10THV IXTA76P10T IXTP76P10T IXTH76P10T

 $V_{DSS} = -100V$   $I_{D25} = -76A$   $R_{DS(co)} \le 25m\Omega$ 

P-Channel Enhancement Mode Avalanche Rated



| TO-268HV<br>(IXTT)  | G S D (Tab) |
|---------------------|-------------|
| TO-263 AA<br>(IXTA) | G S D (Tab) |

| Symbol                                       | Test Conditions   | Maximum Ratings |           |  |
|--|---|-----------------|-----------|--|
| V <sub>DSS</sub>                             | $T_{J} = 25^{\circ}C \text{ to } 150^{\circ}C$                  | - 100           | V         |  |
| $V_{DGR}$                                    | $T_J = 25^{\circ}C$ to 150°C, $R_{gS} = 1M\Omega$               | - 100           | V         |  |
| V <sub>GSS</sub>                             | Continuous  | ±15             | V         |  |
| V <sub>GSM</sub>                             | Transient   | ±25             | V         |  |
| I <sub>D25</sub>                             | T <sub>C</sub> = 25°C   | - 76            | Α         |  |
| I <sub>DM</sub>                              | $T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$ | - 230           | Α         |  |
| IA   | T <sub>c</sub> = 25°C   | - 38            | Α         |  |
| E <sub>AS</sub>                              | $T_{c} = 25^{\circ}C$   | 1               | J         |  |
| $\mathbf{P}_{\scriptscriptstyle \mathrm{D}}$ | $T_{c} = 25^{\circ}C$   | 298             | W         |  |
| T <sub>J</sub>                               |   | -55 +150        | °C        |  |
| T <sub>JM</sub>                              |   | 150             | °C        |  |
| T <sub>stg</sub>                             |   | -55 +150        | °C        |  |
| TL   | Maximum Lead Temperature for Soldering                          | 300             | °C        |  |
| T <sub>SOLD</sub>                            | 1.6 mm (0.062in.) from Case for 10s                             | 260             | °C        |  |
| M <sub>d</sub>                               | Mounting Torque (TO-220 & TO-247)                               | 1.13 /10        | Nm/lb.in. |  |
| Weight                                       | TO-263  | 2.5             | g         |  |
|  | TO-220  | 3.0             | g         |  |
|  | TO-268HV<br>TO-247  | 4.0<br>6.0      | g         |  |
|  | 10-241  | 0.0             | g         |  |

| TO-220AB<br>(IXTP) | 3       |
|--------------------|---------|
| G <sub>DS</sub>    | D (Tab) |
| G D S              | D (Tab) |

| G | = Gate   | D   | = | Drain |
|---|----------|-----|---|-------|
| S | = Source | Tab | = | Drain |

#### **Features**

- International Standard Packages
- Avalanche Rated
- Extended FBSOA
- Fast Intrinsic Diode
- $^{\bullet}$  Low  $\rm R_{\rm \scriptscriptstyle DS(ON)}$  and  $\rm Q_{\rm \scriptscriptstyle G}$

#### **Advantages**

- Easy to Mount
- Space Savings

#### **Applications**

- High-Side Switching
- Push Pull Amplifiers
- DC Choppers
- Automatic Test Equipment
- Current Regulators
- Battery Charger Applications

|                     |   | cteristic Values<br>  Typ.   Max. |  |               |    |
|---------------------|---|-----------------------------------|--|---------------|----|
| BV <sub>DSS</sub>   | $V_{gs} = 0V$ , $I_D = -250\mu A$                         | -100                              |  |               | V  |
| V <sub>GS(th)</sub> | $V_{DS} = V_{GS}$ , $I_D = -250\mu A$                     | - 2.0                             |  | - 4.0         | V  |
| I <sub>gss</sub>    | $V_{GS} = \pm 15V, V_{DS} = 0V$                           |                                   |  | ±100          | nΑ |
| I <sub>DSS</sub>    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$ |                                   |  | - 15<br>- 750 | •  |
| R <sub>DS(on)</sub> | $V_{GS} = -10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$      |                                   |  | 25            | mΩ |



|                                      |      |  |                |                    | IV               |
|--------------------------------------|------|--|----------------|--------------------|------------------|
| <b>Symbol</b> (T <sub>J</sub> = 25°0 | C, L | Test Conditions Unless Otherwise Specified)                            | Charac<br>Min. | teristic \<br>Typ. | /alues<br>  Max. |
| g <sub>fs</sub>                      |      | $V_{DS} = -10V, I_{D} = 0.5 \bullet I_{D25}, \text{ Note 1}$           | 35             | 58                 | S                |
| C <sub>iss</sub>                     | )    |  |                | 13.7               | nF               |
| $\mathbf{C}_{oss}$                   | }    | $V_{GS} = 0V, V_{DS} = -25V, f = 1MHz$                                 |                | 890                | pF               |
| C <sub>rss</sub>                     | J    |  |                | 275                | pF               |
| t <sub>d(on)</sub>                   | ١    | Resistive Switching Times  |                | 25                 | ns               |
| t <sub>r</sub>                       |      | •  |                | 40                 | ns               |
| $\mathbf{t}_{d(off)}$                |      | $V_{GS} = -10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$ |                | 52                 | ns               |
| t <sub>f</sub>                       | J    | $R_{g} = 1\Omega$ (External)   |                | 20                 | ns               |
| $\mathbf{Q}_{g(on)}$                 | )    |  |                | 197                | nC               |
| $\mathbf{Q}_{gs}$                    | }    | $V_{gs} = -10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$ |                | 65                 | nC               |
| $\mathbf{Q}_{gd}$                    | J    |  |                | 65                 | nC               |
| R <sub>thJC</sub>                    |      |  |                |                    | 0.42 °C/W        |
| $\mathbf{R}_{\mathrm{thCS}}$         |      | TO-220   |                | 0.50               | °C/W             |

#### Source-Drain Diode

Note

TO-247

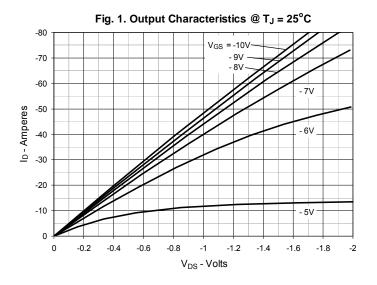
| <b>Symbol Test Conditions</b> (T <sub>J</sub> = 25°C, Unless Otherwise Specified)                   |   | Chara<br>Min. | Characteristic Values<br>Min.   Typ.   Max. |       |               |
|---|---|---------------|---|-------|---------------|
| I <sub>s</sub>  | $V_{GS} = 0V$   |               |   | - 76  | A             |
| I <sub>SM</sub>   | Repetitive, Pulse Width Limited by $T_{JM}$                           |               |   | - 304 | Α             |
| V <sub>SD</sub>   | $I_{\rm F} = -38A, V_{\rm GS} = 0V, \text{ Note 1}$                   |               |   | -1.3  | V             |
| $\left\{ egin{array}{c} \mathbf{t}_{rr} \\ \mathbf{Q}_{RM} \\ \mathbf{I}_{RM} \end{array} \right\}$ | $I_F = -38A$ , $-di/dt = -100A/\mu s$<br>$V_R = -50V$ , $V_{GS} = 0V$ |               | 70<br>215<br>- 6                            |       | ns<br>nC<br>A |

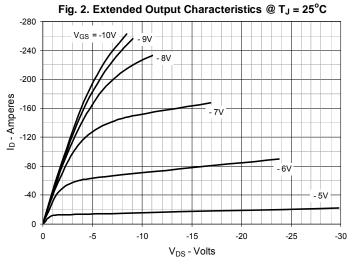
1: Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .

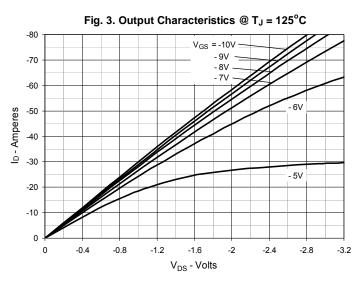
0.21

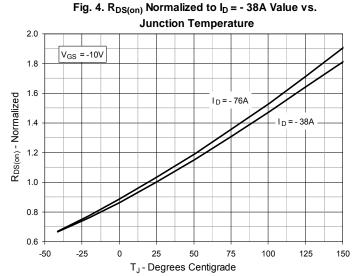
°C/W

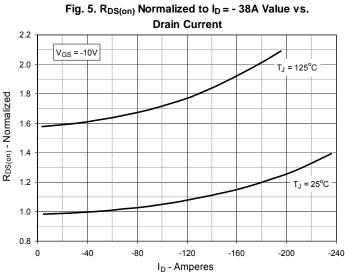


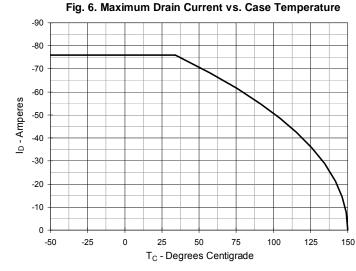








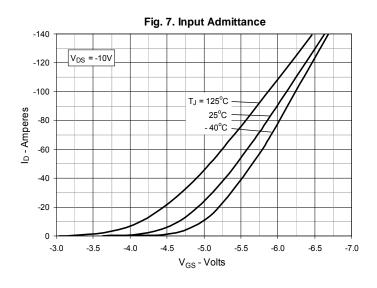


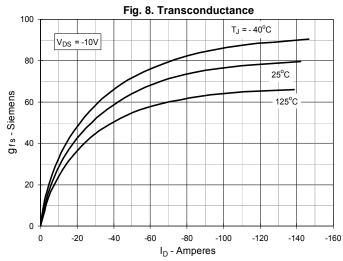


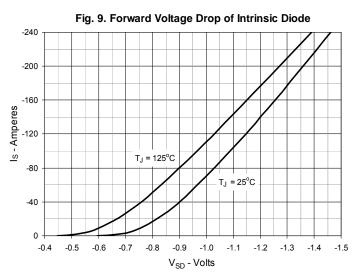
. 5. K<sub>DS(on)</sub> Normalized to I<sub>D</sub> = - 38A value vs.

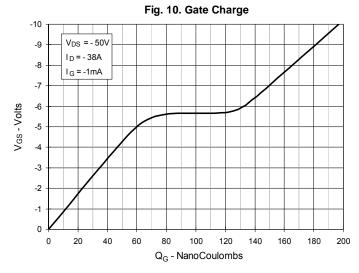
Fig. 6. Maximum Drain Current vs. Case Temperatu

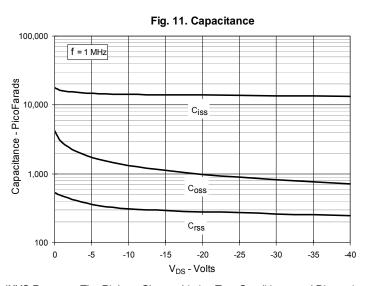


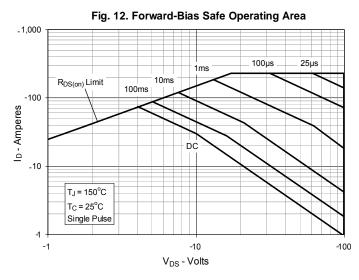












IXYS Reserves The Right to Change Limits, Test Conditions, and Dimensions.



## IXTT76P10THV IXIXTP76P10T IX

## IXTA76P10T IXTH76P10T

Fig. 13. Resistive Turn-on Rise Time vs.
Junction Temperature

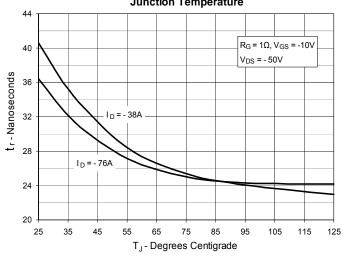


Fig. 14. Resistive Turn-on Rise Time vs.

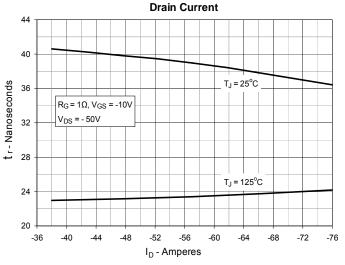


Fig. 15. Resistive Turn-on Switching Times vs.

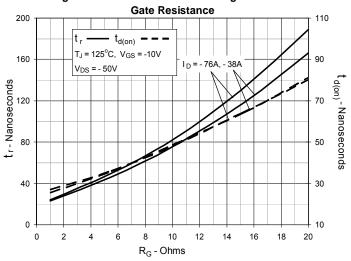


Fig. 16. Resistive Turn-off Switching Times vs.
Junction Temperature

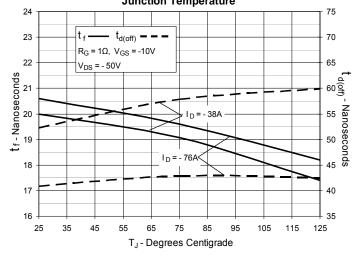


Fig. 17. Resistive Turn-off Switching Times vs.

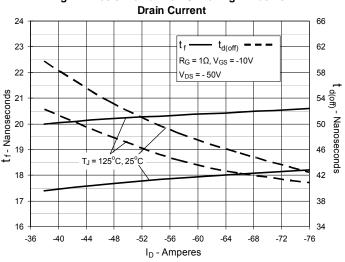


Fig. 18. Resistive Turn-off Switching Times vs.

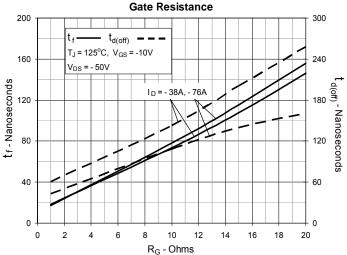
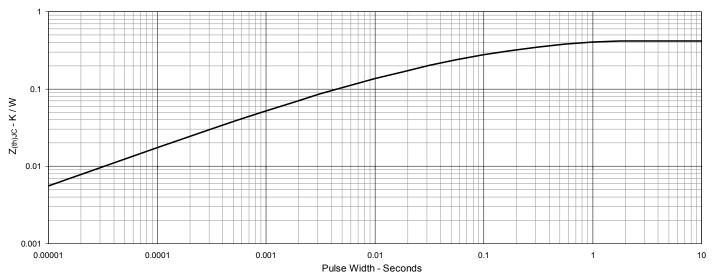


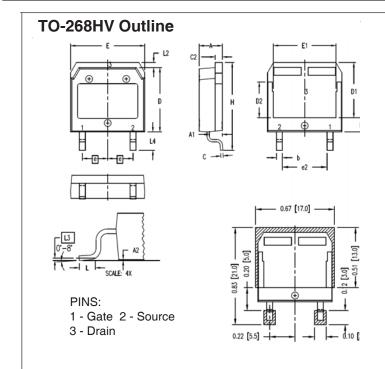
Fig. 19. Maximum Transient Thermal Impedance





## IXTT76P10THV IXTP76P10T

### IXTA76P10T IXTH76P10T



| SYM       | INCHES            |               | MILLIMETER |              |
|-----------|-------------------|---------------|------------|--------------|
| STM       | MIN               | MAX           | MIN        | MAX          |
| Α         | .193              | .201          | 4.90       | 5.10         |
| A1        | .106              | .114          | 2.70       | 2.90         |
| A2        | .001              | .010          | 0.02       | 0.25         |
| Ь         | .045              | .057          | 1.15       | 1.45         |
| С         | .016              | .026          | 0.40       | 0.65         |
| C2        | .057              | .063          | 1.45       | 1.60         |
| D         | .543              | .551          | 13.80      | 14.00        |
| D1        | .465              | .476          | 11.80      | 12.10        |
| D2        | .295              | .307          | 7.50       | 7.80         |
| D3        | .114              | .126          | 2.90       | 3.20         |
| E         | .624              | .632          | 15.85      | 16.05        |
| E1        | .524              | .535          | 13.30      | 13.60        |
| е         | .215 BSC          |               | 5.45 BSC   |              |
| (e2)      | .374              | .386          | 9.50       | 9.80         |
| Η         | .736              | .752          | 18.70      | 19.10        |
| L         | .067              | .079          | 1.70       | 2.00         |
| L2        | .039              | .0 <b>4</b> 5 | 1.00       | 1.15         |
| <u>L3</u> | .010 BSC 0.25 BSC |               |            | BSC          |
| L4        | .150              | .161          | 3.80       | <b>4</b> .10 |

